Revision 1.00

GAIN CHIPS AR coated Fabry-Perot Laser

General Product Information					
Product	Application				
tunable 790 nm Fabry-Perot Laser	Spectroscopy				
for use in an External Cavity Diode Laser (ECDL)					
sealed SOT Housing					
Monitor Diode					

Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T _C	°C	-20		50
Forward Current	I _F	mA			200
Reverse Voltage	V _R	V			0
Output Power (extracavity)	P _{opt}	mW			70

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		40
Forward Current	۱ _F	mA			180

Characteristics extracavity at 25° C at Begin Of Life under recommended working point, with external cavity

λ_{c}	nm		790	
$\Delta\lambda_{tun}$	nm	760		795
P _{opt}	mW		50	
			TM	
			TEM ₀₀	
	$\Delta\lambda_{tun}$	$\Delta \lambda_{tun}$ nm	$\Delta\lambda_{tun}$ nm 760	$\begin{array}{c c} \Delta \lambda_{tun} & nm & 760 \\ \hline P_{opt} & mW & 50 \\ \hline TM \end{array}$



Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings can cause permanent damage to the device. Please note that a damaging optical power level may occur although the maximum current is not reached.

Measurement Conditions / Comments

Measurement Conditions / Comments

The actual achieved wavelength and power are strongly influenced by the external cavity. eagleyard Photonics gives no guarantee on these parameters.

E field perpendicular to Pin 2 - Pin 3 - plane Fundamental Mode

© All rights reserved by eagleyard Photonics GmbH. This data sheet will be electronically administered and is subject to change without notice. Uncontrolled copy when printed.

eagleyard Photonics GmbH

Rudower Chaussee 29 12489 Berlin GERMANY fon +49. 30. 6392 4520 fax +49. 30. 6392 4529

info@toptica-eagleyard.com www.toptica-eagleyard.com



15.04.2019

Revision 1.00

GAIN CHIPS AR coated Fabry-Perot Laser

Amplified Spontaneous Emission (ASE) without external cavity						
Parameter	Symbol	Unit	min	typ	max	
Divergence parallel (FWHM)	$\Theta_{ }$	0		10		
Divergence perpendicular (FWHM)	Θ_{\perp}	0		22		
Monitor Detector Responsivity	I _{mon} / P _{opt}	μA / mW	1		40	

Measurement Conditions / Commentsparallel to Pin 2 - Pin 3 plane (see p. 3)perpendicular to Pin 2 - Pin 3 plane (see p. 3) $U_{R MD} = 5 V$

Chip Parameter

Parameter	Symbol	Unit	min	typ	max
Cavity Length	L	μm		1500	
Reflectivity at Front Facet	R _{ff}			3 [.] 10 ⁻⁴	1·10 ⁻³

Measurement Conditions / Comments

© All rights reserved by eagleyard Photonics GmbH. This data sheet will be electronically administered and is subject to change without notice. Uncontrolled copy when printed.



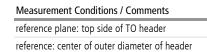
15.04.2019



Revision 1.00

GAIN CHIPS AR coated Fabry-Perot Laser

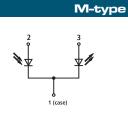
Symbol	Unit	min	typ	max
d _{EP}	mm	3.50	3.65	3.70
R	mm			0.12
I _{PIN}	mm		14	
	d _{EP} R	d _{ep} mm R mm	d _{EP} mm 3.50 R mm	d _{EP} mm 3.50 3.65 R mm

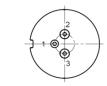


Package Pinout

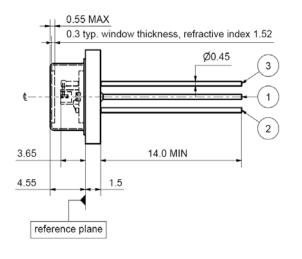
1 Laser Diode Cathode, Monitor Diode Cathode, Case

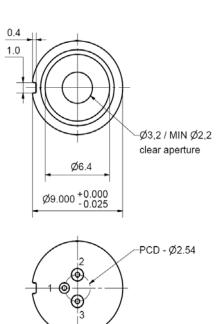
- 2 Photo Diode Anode
- 3 Laser Diode Anode





Package Drawings





© All rights reserved by eagleyard Photonics GmbH. This data sheet will be electronically administered and is subject to change without notice. Uncontrolled copy when printed.

eagleyard Photonics GmbH

Rudower Chaussee 29 12489 Berlin GERMANY fon +49. 30. 6392 4520 fax +49. 30. 6392 4529

info@toptica-eagleyard.com www.toptica-eagleyard.com





Revision 1.00

GAIN CHIPS AR coated Fabry-Perot Laser





Typical Measurement Results ex cavity 140 2.1 25_I180mA_770 nm_Li 25_I180mA_775 nm_Li 120 1 8 -20 100 1.5 power signal in dBm -40 Мш 1.2 > 80 oltade power 60 -60 0.6 -80 20 0.3 −100 ∟ 730 0.0 790 810 820 740 750 780 800 760 770 83 20 80 100 120 140 160 180 current in mA ength in nm wavel

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.

The RWE diode type is known to be sensitive against thermal stress. It should not be operated without appropriate optical feedback from an external cavity. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.

Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.



© All rights reserved by eagleyard Photonics GmbH. This data sheet will be electronically administered and is subject to change without notice. Uncontrolled copy when printed.

eagleyard Photonics GmbH

Rudower Chaussee 29 12489 Berlin GERMANY fon +49. 30. 6392 4520 fax +49. 30. 6392 4529

info@toptica-eagleyard.com www.toptica-eagleyard.com